

isc Silicon NPN Darlington Power Transistor

2SD1124

DESCRIPTION

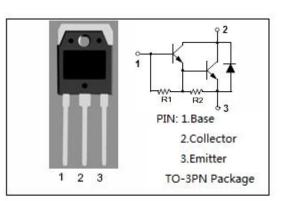
- Collector-Emitter Sustaining Voltage-
- : V_{CEO(SUS)}= 80V(Min)
- High DC Current Gain
- : h_{FE}= 1000(Min) @I_C= 1A
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

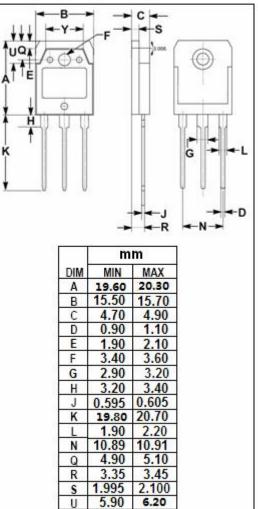
APPLICATIONS

• Designed for general-purpose amplifier and low-speed switching applications

ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER VAL		UNIT	
V _{CBO}	Collector-Base Voltage	80	V	
V _{CEO}	Collector-Emitter Voltage	80	V	
V _{EBO}	Emitter-Base Voltage	6	V	
Ic	Collector Current-Continuous	8	A	
I _{CM}	Collector Current-Peak	12	A	
Pc	Collector Power Dissipation @ T_c =25°C	80	W	
TJ	Junction Temperature	150	°C	
T _{stg}	Storage Temperature Range	-55~150	°C	





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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	МАХ	UNIT
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	I _E = 5mA; I _C = 0	6			V
V _{(BR)CBO}	Collector - Base Breakdown Voltage	I _C = 0.1mA; I _E = 0	80			V
V _{CEO(SUS)}	Collector-Emitter Sustaining Voltage	I _C = 30mA; I _B = 0	80			V
V _{CE(sat)-1}	Collector-Emitter Saturation Voltage	I _C = 4A; I _B = 16mA			2.0	V
V _{CE(sat)-2}	Collector-Emitter Saturation Voltage	I _C = 6A, I _B = 30mA			3.0	V
V _{BE(on)}	Base-Emitter On Voltage	I _C = 4A; V _{CE} = 4V			2.5	V
I _{CEO}	Collector Cutoff Current	V _{CE} = 80V; I _B = 0			0.1	mA
І _{сво}	Collector Cutoff Current	V_{CB} = 80V; I _E = 0			0.1	mA
I _{EBO}	Emitter Cutoff Current	V _{EB} = 5V; I _C = 0			5.0	mA
h _{FE -1}	DC Current Gain	I _C = 1A; V _{CE} = 4V	1000			
h _{FE} -2	DC Current Gain	I _C = 4A; V _{CE} = 4V	500			

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